

## X-Band Low Noise Amplifier

### 8 - 12 GHz

Rev. V3

### Features

- 1.6 dB Noise Figure
- Single +4 V Bias @ 60 mA
- Fully internally matched to 50  $\Omega$
- Lead-Free 3 mm 16-Lead PQFN Package
- Halogen-Free “Green” Mold Compound
- RoHS\* Compliant and 260°C Reflow Compatible

### Description

The MAAL-010528 is a high performance X-band GaAs LNA, housed in a miniature, lead-free 3 mm PQFN surface mount plastic package. This MMIC operates from 8 to 12 GHz providing a nominal gain of 20 dB with excellent gain flatness, high OIP3 linearity of 26 dBm, and a mid-band noise figure of 1.6 dB. The part features a self-bias architecture which requires only a single, positive supply. The device is internally matched to 50  $\Omega$  input/ output and is well suited to multiple applications including Vsat, radar and microwave radios due to the part's ease of use and excellent performance parameters.

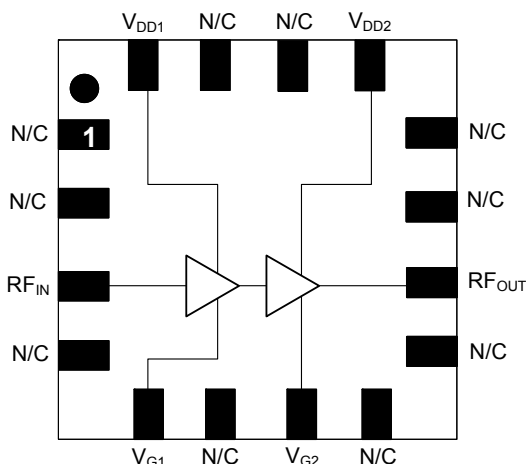
### Ordering Information <sup>1,2</sup>

| Part Number        | Package        |
|--------------------|----------------|
| MAAL-010528-TR0500 | 500 piece reel |
| MAAL-010528-001SMB | Sample Board   |

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

\* Restrictions on Hazardous Substances,  
European Union Directive 2002/95/EC.

### Functional Schematic



### Pin Configuration

| Pin No.             | Pin Name          | Description    |
|---------------------|-------------------|----------------|
| 1                   | N/C               | No Connection  |
| 2                   | N/C               | No Connection  |
| 3                   | RF <sub>IN</sub>  | RF Input       |
| 4                   | N/C               | No Connection  |
| 5 <sup>3,4</sup>    | V <sub>G1</sub>   | Gate Voltage 1 |
| 6                   | N/C               | No Connection  |
| 7 <sup>3,4</sup>    | V <sub>G2</sub>   | Gate Voltage 2 |
| 8                   | N/C               | No Connection  |
| 9                   | N/C               | No Connection  |
| 10                  | RF <sub>OUT</sub> | RF Output      |
| 11                  | N/C               | No Connection  |
| 12                  | N/C               | No Connection  |
| 13                  | V <sub>DD2</sub>  | Bias Voltage 2 |
| 14                  | N/C               | No Connection  |
| 15                  | N/C               | No Connection  |
| 16                  | V <sub>DD1</sub>  | Bias Voltage 1 |
| Paddle <sup>5</sup> | RF and DC Ground  |                |

3. For self-bias, external components C7 through C12 are optional. No V<sub>G</sub> bias is needed. If C7 through C12 are removed, traces must also be removed.
4. For optional adjustment of self-bias, apply D.C. gate voltage between -1 V and +0.3 V. External components C7 through C12 are required.
5. The exposed pad centered on the package bottom must be connected to RF and DC ground.

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**Electrical Specifications:  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 4\text{ V}$ ,  $Z_0 = 50\ \Omega$** 

| Parameter          | Test Conditions           | Units | Min. | Typ.              | Max.              |
|--------------------|---------------------------|-------|------|-------------------|-------------------|
| Gain               | 8 - 12 GHz                | dB    | 17.5 | 20                | —                 |
| Noise figure       | 8 GHz<br>10 GHz<br>12 GHz | dB    | —    | 1.5<br>1.8<br>2.1 | 2.0<br>2.3<br>2.8 |
| Input Return Loss  | 8 - 12 GHz                | dB    | —    | 10                | —                 |
| Output Return Loss | 8 - 12 GHz                | dB    | —    | 13                | —                 |
| P1dB               | 8 - 12 GHz                | dBm   | —    | 14                | —                 |
| OIP3               | 8 - 12 GHz                | dBm   | —    | 26                | —                 |
| Current            | —                         | mA    | —    | 60                | 75                |

**Absolute Maximum Ratings<sup>6,7</sup>**

| Parameter             | Absolute Maximum |
|-----------------------|------------------|
| Input Power           | +22 dBm          |
| Operating Voltage     | 6 V              |
| Operating Temperature | -40°C to +85°C   |
| Storage Temperature   | -65°C to +150°C  |

6. Exceeding any one or combination of these limits may cause permanent damage to this device.  
 7. M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.

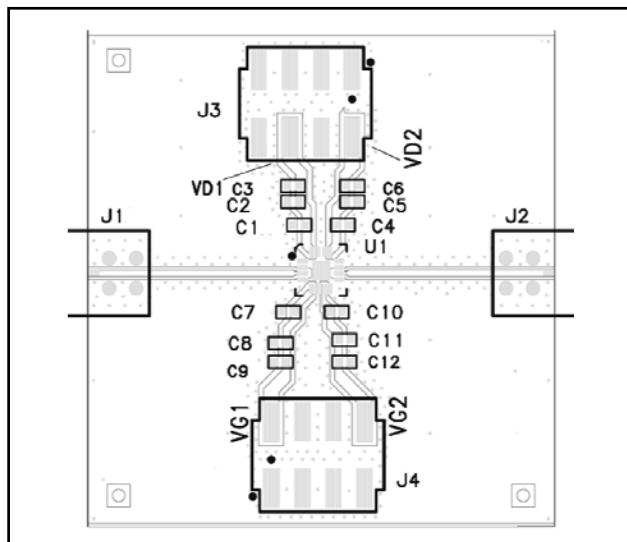
**Handling Procedures**

Please observe the following precautions to avoid damage:

**Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1B devices.

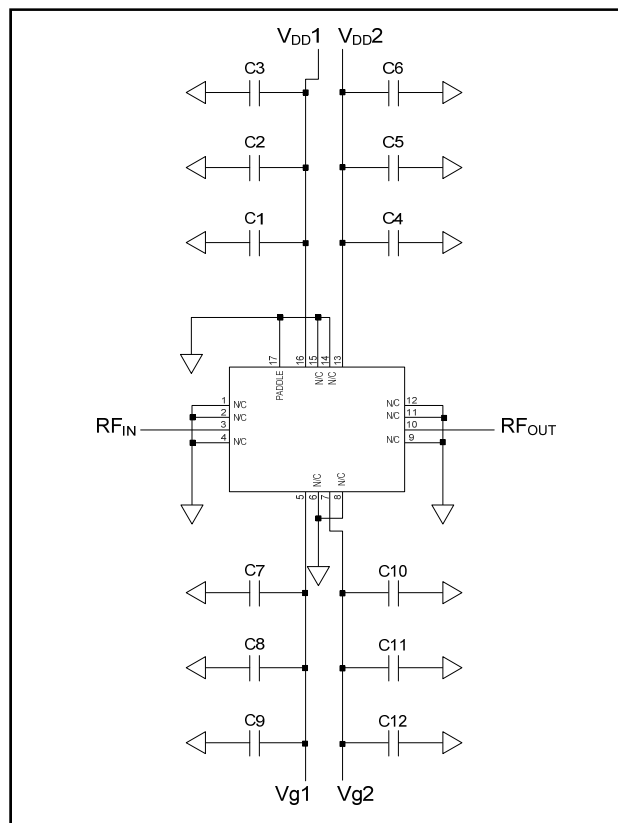
## Recommended PCB



## Parts List

| Component       | Value        | Package |
|-----------------|--------------|---------|
| C1, C4, C7, C10 | 2.2 pF       | 0402    |
| C2, C5, C8, C11 | 100 pF       | 0402    |
| C3, C6, C9, C12 | 0.01 $\mu$ F | 0402    |

## Application Schematic<sup>8,9</sup>



8. For self-bias, external components C7 through C12 are optional. No  $V_G$  bias is needed. If C7 through C12 are removed, traces must also be removed.
9. For optional adjustment of self-bias, apply D.C. gate voltage between  $-1$  V and  $+0.3$  V. External components C7 through C12 are required.

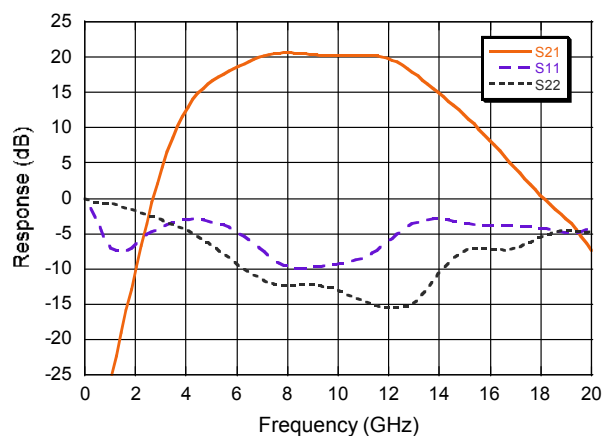
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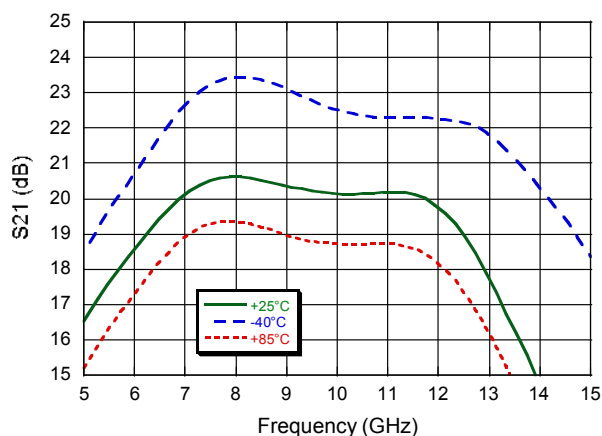
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### Typical Performance Curves

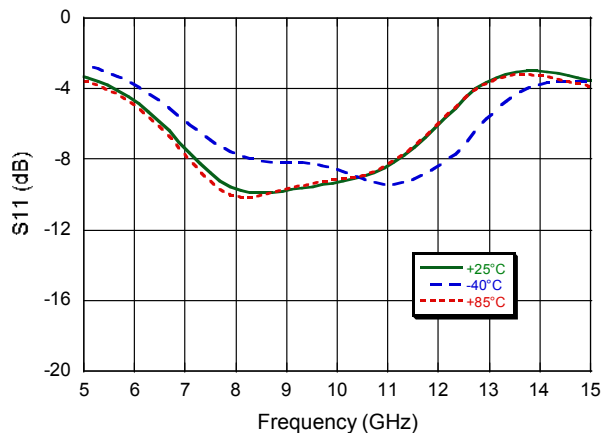
#### Wide-Band Gain and Return Loss



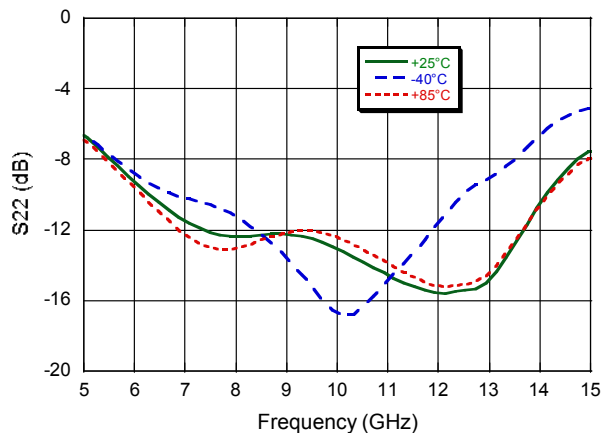
#### Small-Signal Gain vs. Temperature



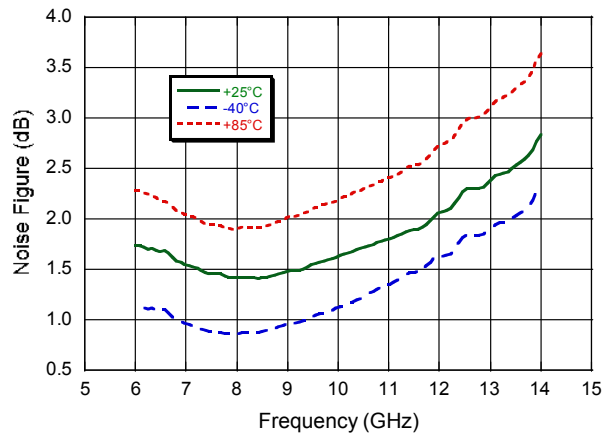
#### Input Return Loss vs. Temperature



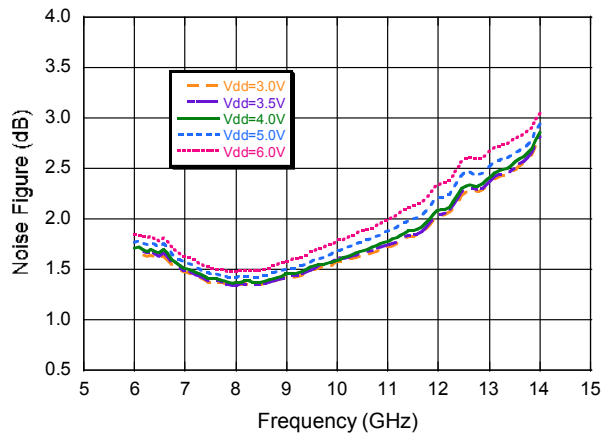
#### Output Return Loss vs. Temperature



#### Noise Figure vs. Temperature

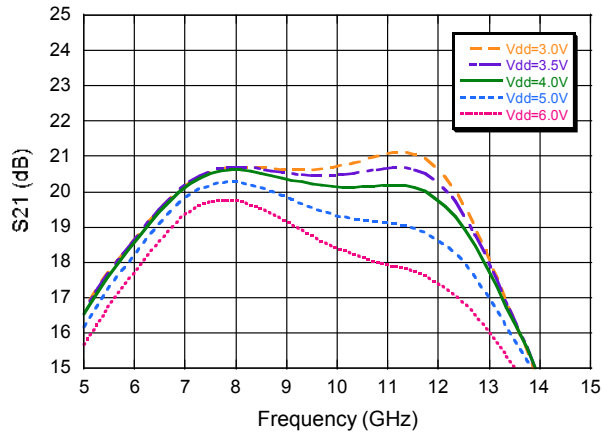


#### Noise Figure vs. Supply Voltage

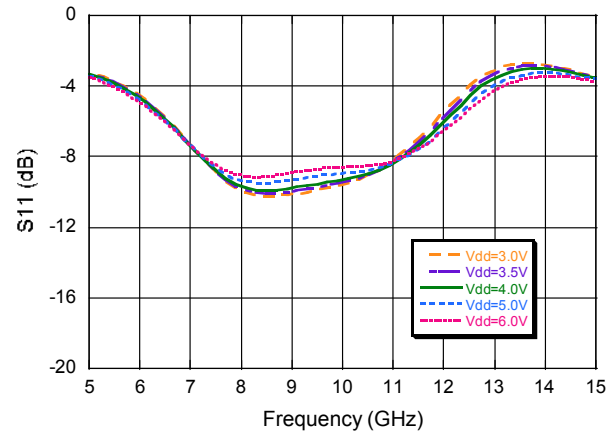


## Typical Performance Curves

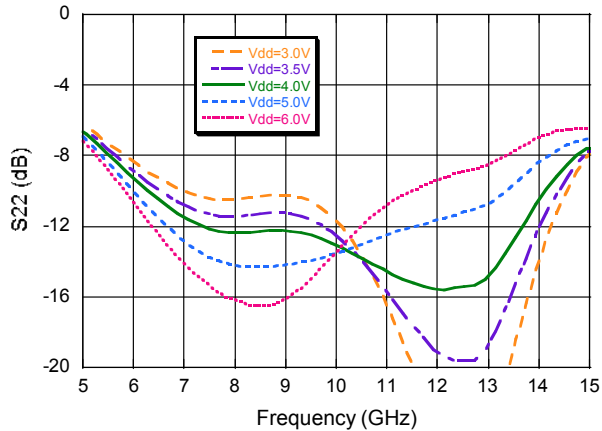
**Small-Signal Gain vs. Supply Voltage**



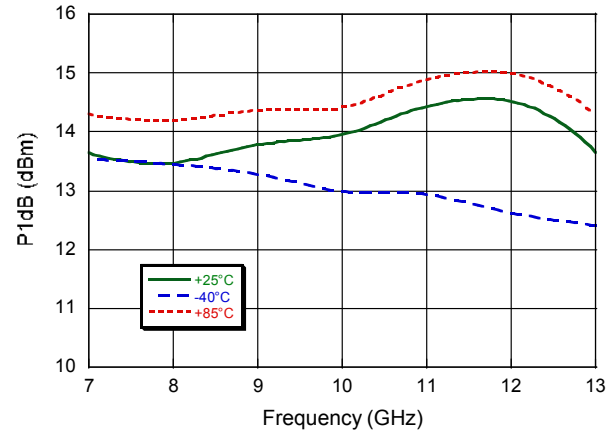
**Input Return Loss vs. Supply Voltage**



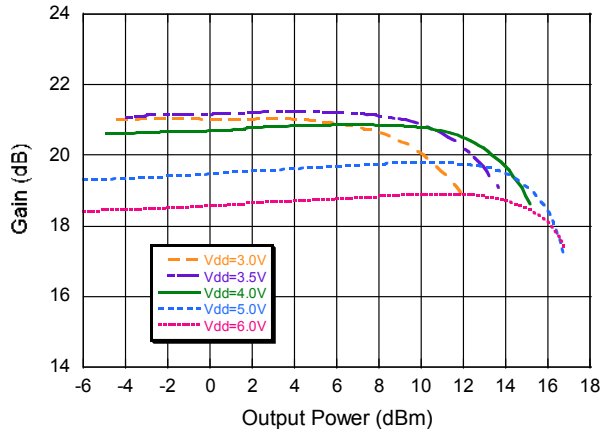
**Output Return Loss vs. Supply Voltage**



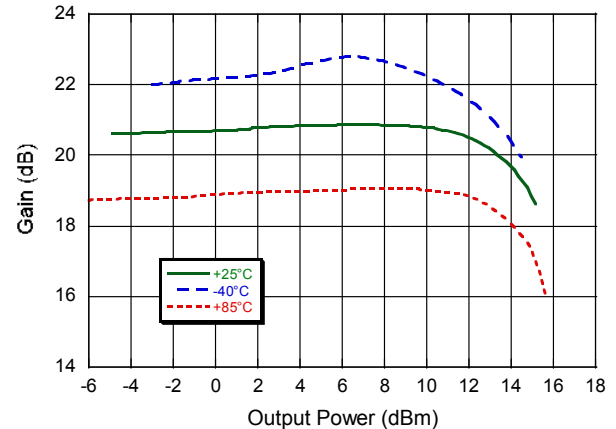
**P1dB vs. Temperature**



**Large-Signal Gain vs. Voltage @ 10 GHz**



**Large-Signal Gain vs. Temperature @ 10 GHz**

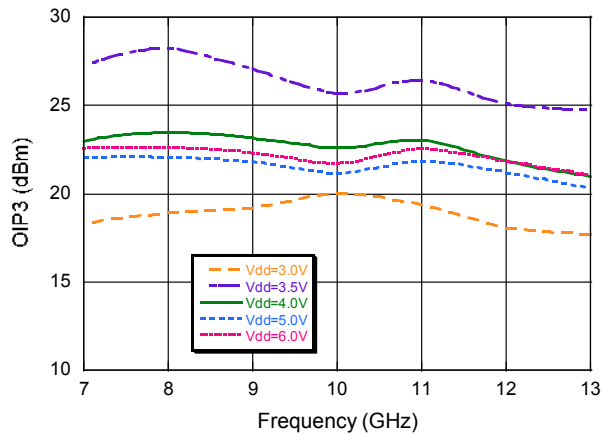


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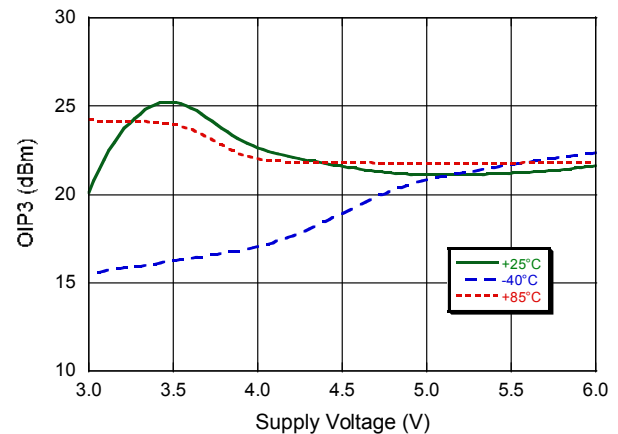
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## Typical Performance Curves

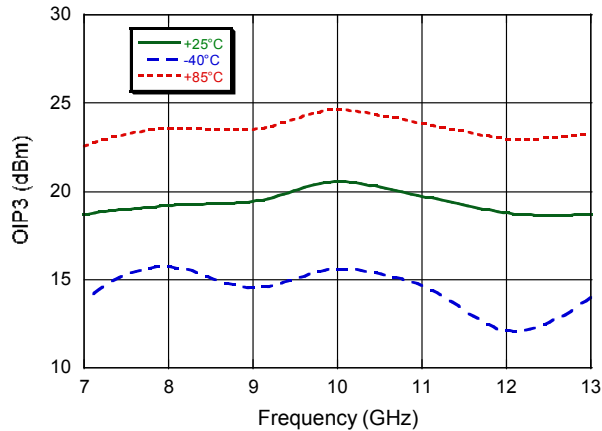
Output IP3 vs. Supply Voltage



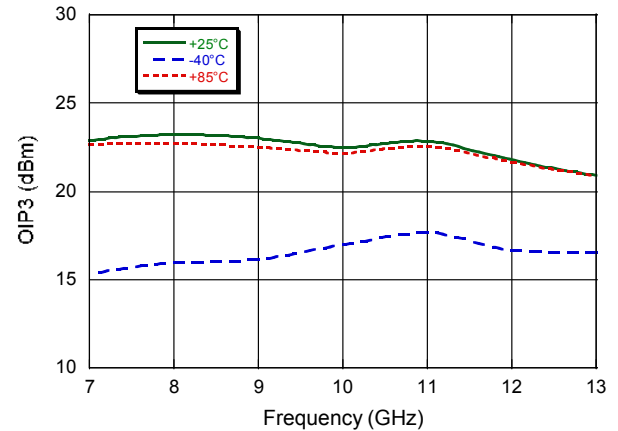
Output IP3 vs. Temperature @ 10 GHz



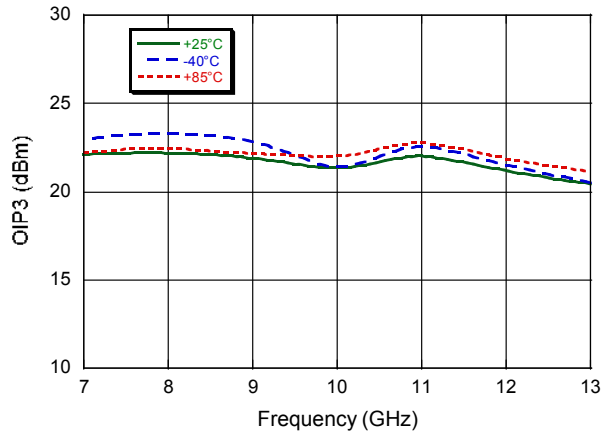
Output IP3 vs. Temperature for V<sub>DD</sub> = 3 V



Output IP3 vs. Temperature for V<sub>DD</sub> = 4 V



Output IP3 vs. Temperature for V<sub>DD</sub> = 5 V



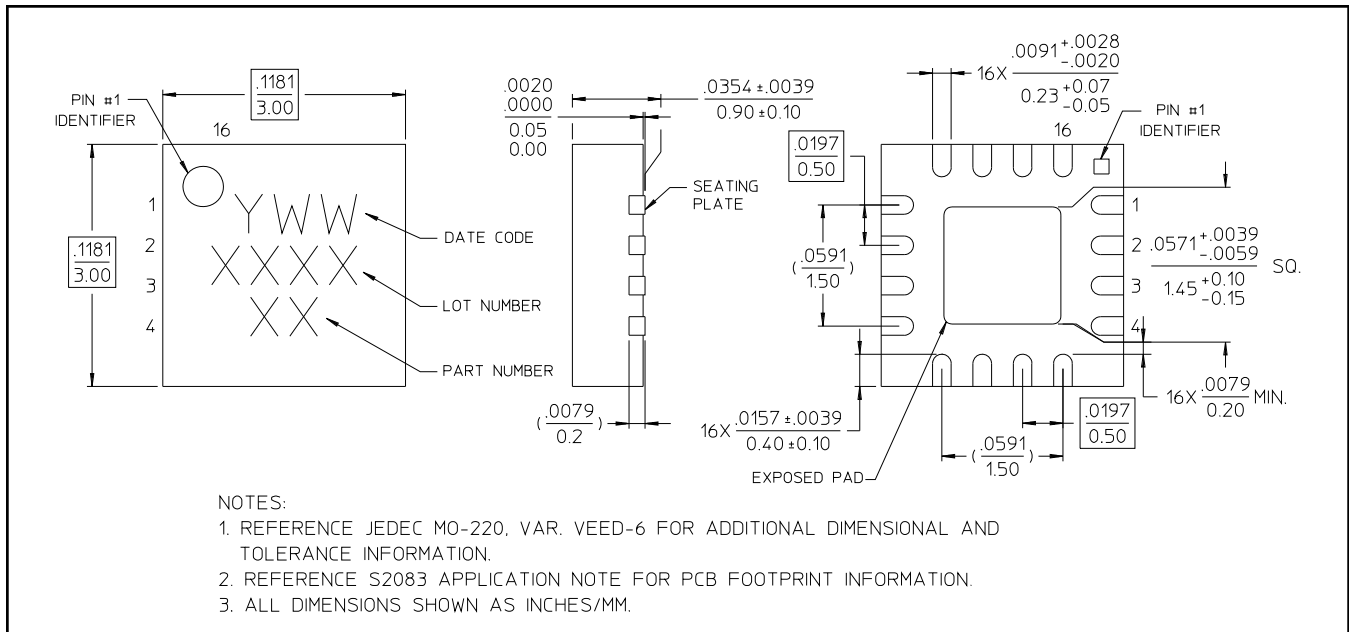
## Typical Bias Current vs. Supply Voltage

| V <sub>DD1</sub> = V <sub>DD2</sub> (V) | I <sub>DD1</sub> (mA) | I <sub>DD2</sub> (mA) |
|-----------------------------------------|-----------------------|-----------------------|
| 3                                       | 14.6                  | 43.4                  |
| 4                                       | 15.2                  | 44.5                  |
| 5                                       | 15.6                  | 45.0                  |
| 6                                       | 15.8                  | 45.1                  |

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### Lead-Free 3 mm 16-Lead PQFN<sup>†</sup>



<sup>†</sup> Reference Application Note S2083 for lead-free solder reflow recommendations.  
Meets JEDEC moisture sensitivity level 1 requirements.  
Plating is 100% matte tin plating over copper

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- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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